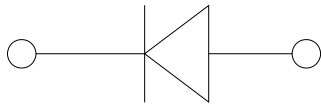
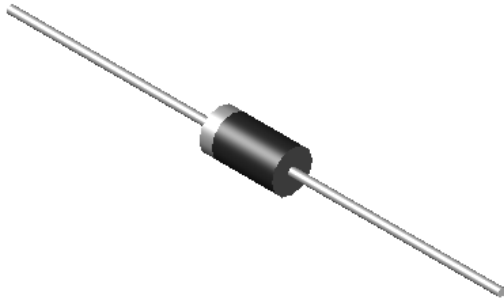


General Purpose Rectifier



Features

- High efficiency
- High current capability
- High reliability
- High surge current capability
- Low power loss
- Glass passivated chip junction
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Mechanical Data

- **Package:** DO-201AD(DO-27)
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** Color band denotes cathode end

■ Maximum Ratings (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	1N5400G	1N5401G	1N5402G	1N5404G	1N5406G	1N5407G	1N5408G
Device marking code			1N5400G	1N5401G	1N5402G	1N5404G	1N5406G	1N5407G	1N5408G
Repetitive Peak Reverse Voltage	VRRM	V	50	100	200	400	600	800	1000
Average Forward Current @60Hz sine wave, Resistance load, T _a =75°C	I _{F(AV)}	A	3.0						
Surge(Non-repetitive)Forward Current @ 60Hz Half-sine wave, 1 cycle, T _a =25°C	IFSM	A	200						
Storage Temperature	T _{stg}	°C	-55 ~+150						
Junction Temperature	T _j	°C	-55~+150						

■ Electrical Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	1N5400G	1N5401G	1N5402G	1N5404G	1N5406G	1N5407G	1N5408G
Maximum instantaneous forward voltage drop per diode	V _{FM}	V	I _{FM} =3.0A	1.1						
Maximum DC reverse current at rated DC blocking voltage per diode	I _{RRM1}	μA	T _a =25°C	2.5						
	I _{RRM2}		T _a =125°C	50						
Typical junction capacitance	C _j	pF	Measured at 1MHZ and Applied Reverse Voltage of 4.0 V.D.C.	50						

■ Thermal Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	1N5400G	1N5401G	1N5402G	1N5404G	1N5406G	1N5407G	1N5408G
Thermal Resistance(Typical)	R _{θJ-A}	°C/W	30						



1N5400G THRU 1N5408G

Ordering Information (Example)

PREFERRED P/N	PACKAGE CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
1N5400G~1N5408G	D1	Approximate 1.05	1250	1250	12500	Tape
1N5400G~1N5408G	C1	Approximate 1.05	250	250	12500	Bulk

Characteristics (Typical)

FIG.1: I_o - T_a Curve

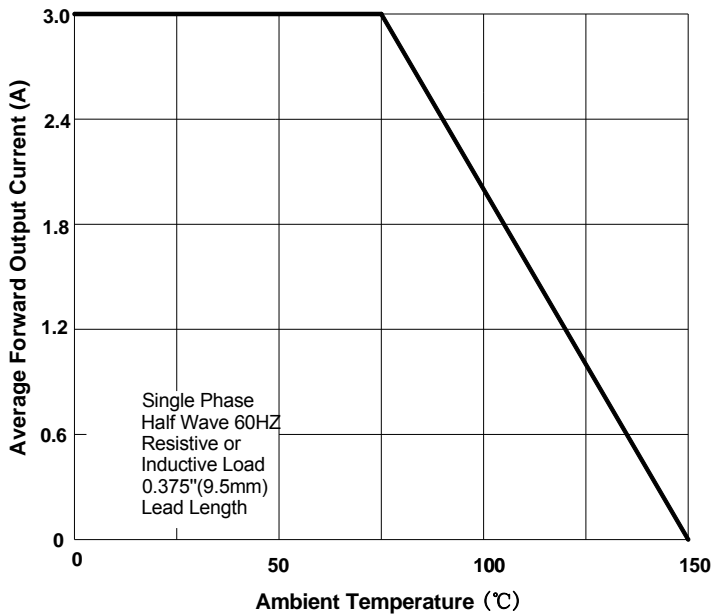


FIG.2: Surge Forward Current Capability

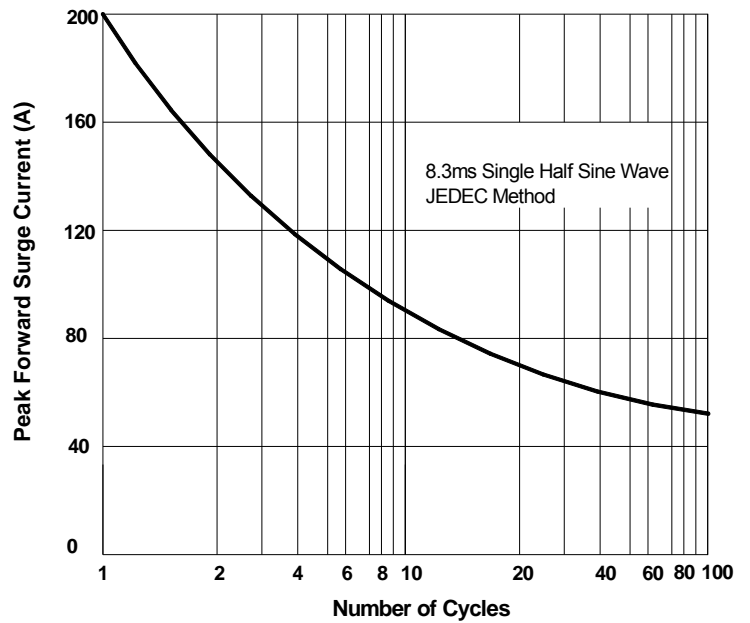


FIG.3: Forward Voltage

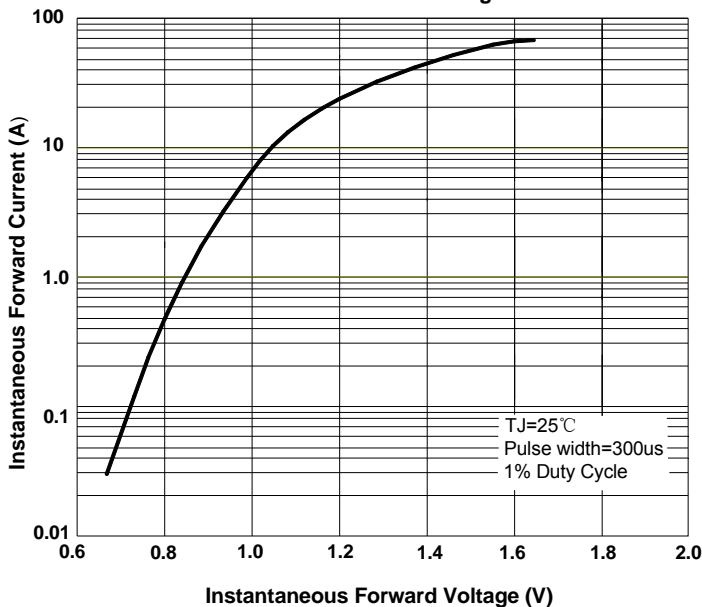
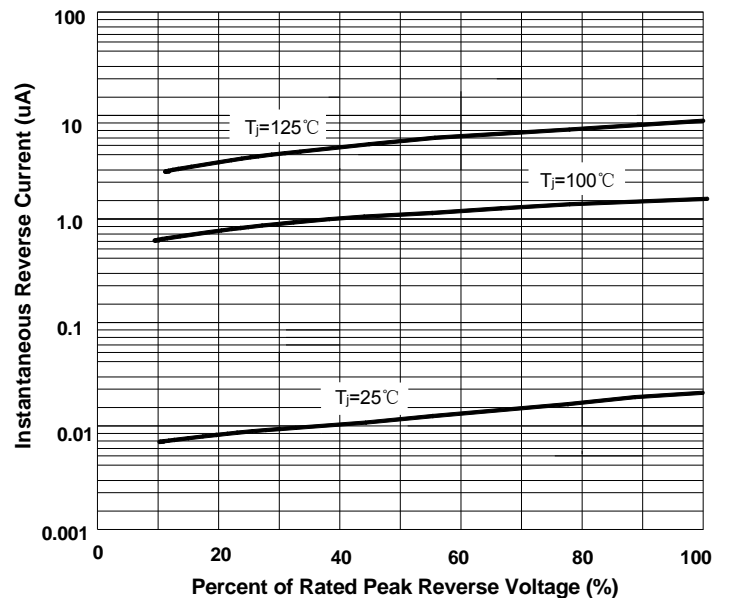


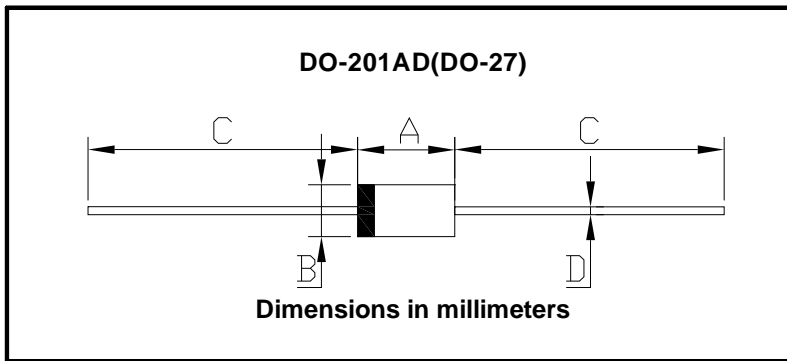
FIG.4: Typical Reverse Characteristics





1N5400G THRU 1N5408G

■ Outline Dimensions



DO-201AD(DO-27)		
Dim	Min	Max
A	8.50	9.50
B	5.00	5.60
C	25.4	/
D	1.20	1.30



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